

OptiMOS[™]-7 40V in SSO8 HB 5x6

Half-bridge configuration with high current capability up to 100A as perfect layout for 3-phase Automotive drive applications

Infineon Technologies AG (FSE: IFX / OTCQX: IFNNY) is extending its Automotive MOSFET technology generation OptiMOS™-7 40V in industry standard SSO8 HB 5x6 (PG-TDSON-8) robust power packages.

The Automotive standard SSO8 HB 5x6 package offers two N-channel MOSFETs in H-bridge configuration at a very high current of up to 100A.

OptiMOS™-7 40V in SSO8 HB 5x6 offers highest power density and energy efficiency at the industry's lowest on-state resistance on a 5x6 mm² footprint. Infineon's SSO8 HB 5x6 leading robust Automotive packages offer lowest costs per channel at best quality for Automotive design.

Furthermore, SSO8 HB 5x6 in OptiMOS™-7 40V offers reduced switching losses, improved SOA ruggedness and high avalanche current capability to facilitate efficient system designs for tomorrow's Automotive applications.

IAUCN04S7L025AH is a special design with an asymmetric H-bridge for Automotive USB-charging applications.

The SSO8 HB 5x6 in OptiMOS™-7 40V product family focuses on very costefficient power Automotive applications, especially body control drives, window-lift, power-lift gate, power-seat, electric parking brake, USB-charging, water pumps and in principle all cost efficient & small BLDC drives for tomorrow's Automotive applications in CO₂-friendly vehicles.

The product family of OptiMOS™-7 40V in the SSO8 HB 5x6 package ranges from best-in-class 2.3 m Ω to 5.4 m Ω per MOSFET channel.

More information on OptiMOS™-7 40V SSO8 HB 5x6: https://www.infineon.com/package-technology/sso8-5x6













Power lift gate

Window lift

Water pump







Body control

Electric parking brake

DC-DC

Key features

- 5x6 mm² H-bridge footprint
- Up to 100A high current capability
- 2-channel H-bridge configuration
- Leading-edge OptiMOS™-7 40V
- $R_{DS(on)}$ range: 2.3 m Ω 5.4 m Ω
- Robust Cu-clip for lowest package resistance + minimized stray inductance
- High avalanche capability and SOA ruggedness

Key benefits

- Highest power and current density in 5x6 mm² H-bridge
- Optimized layout and form factor
- High thermal capacity lead-frame
- Reduced conduction losses
- Optimized switching behavior
- JEDEC industry standard package
- Automotive robust package & quality by Infineon

Key applications

- Power-lift gate
- Window-lift
- Power-seat
- Water / oil / fuel pump
- Small BLDC drives
- Body control modules
- Electric parking brake
- USB-charging / DC-DC

Product Table

Product name	Voltage [V]	R _{DS(on)} (max) [mOhm]	I _D (max) [A]	Product status
IAUCN04S7L023H	40	2.34	100	active & preferred
IAUCN04S7N024H	40	2.46	100	active & preferred
IAUCN04S7L037H	40	3.78	84	active & preferred
IAUCN04S7N040H	40	4.01	82	active & preferred
IAUCN04S7L050H	40	5.04	65	active & preferred
IAUCN04S7N054H	40	5.41	62	active & preferred
IAUCN04S7L025AH	40	2.56 5.04	100 65	active & preferred



www.infineon.com

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